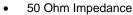
WBA0105B 100 – 550 MHz LOW NOISE WIDE BAND 1 Watt AMPLIFIER

Key Features



- 100 ~ 550 MHz
- 0.80 dB Noise Figure
- 44.0 dBm Output IP₃
- 35.0 dB Gain
- +/-0.3 dB Gain Flatness
- 30.0 dBm P_{1dB}
- 1.25:1 VSWR
- Single DC Power Supply
- >34 Years MTBF
- Unconditional Stable
- RoHS Compliant

Specifications

Summary of the electrical specifications WBA0105B at room temperature

RoHS

Product Description



CAUTION:

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The amplifier is designed to meet the rugged standard of MIL-STD-202g.

Applications

- Mobile Infrastructures
- Broadcast
- CATV/DBS
- Defense
- Security System
- Measurement
- Fixed Wireless



Index	Testing Item	Symbol	Test Constraints		Nom	Max	Unit
1	Gain	S ₂₁	100 – 550 MHz	33	35		dB
2	Gain Variation	ΔG	100 – 550 MHz		+/- 0.3	+/-0.75	dB
3	Input Return Loss	S ₁₁	100 – 550 MHz	18	20		dB
4	Output Return Loss	S ₂₂	100 – 550 MHz	18	20		dB
5	Reverse Isolation	S ₁₂	100 – 550 MHz		45		dB
6	Noise Figure	NF	100 – 550 MHz		0.80	1.1	dB
7	Output 1dB Gain Compression Point	P _{1dB}	100 – 550 MHz	28	30		dBm
8	Output Third Order Interception Point	IP ₃	Two-tone, P _{out} =+10 dBm each, 1 MHz sep.	42	44		dBm
9	Current Consumption	I _{dd}	$V_{dd} = +12V$		260		mA
10	Power Supply Voltage	V _{dd}		+10	+12	+13	V
11	Thermal Resistance, Junction to Case	R _{th,c}	Last stage transistor V_{ds} = 10V, I_{ds} = 220 mA,			30	°C/W
12	Operating Temperature	To		-40		+85	°C
13	Maximum Input CW RF Power	PIN, MAX	DC – 6 GHz			10	dBm

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	-0.5, +13
Drain Current	mA	350
Total Power Dissipation	W	3.5
Input CW RF Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85
Thermal Resistance	°C/W	30

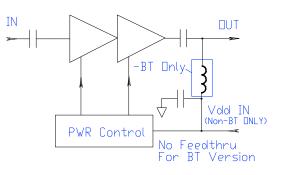
Operation of this device above any one of these parameters may cause permanent damage.

Ordering Information

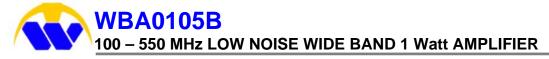
Model	WBA0105B

Contact the Factory for built-in output bias-T configuration.

Functional Block Diagram

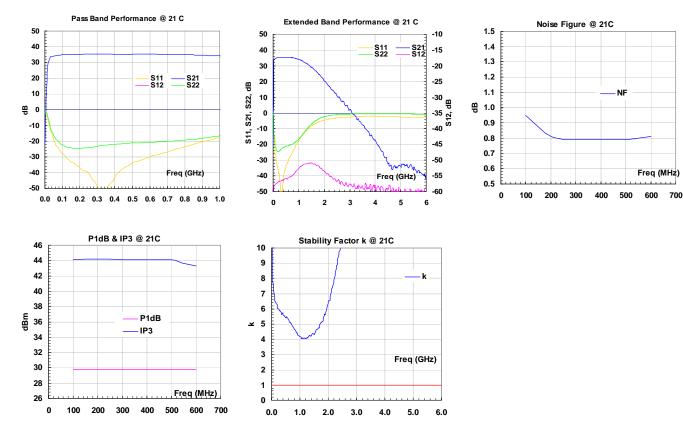


Specifications and information are subject to change without notice.



REV B March 2017

Typical Data



Outline, WP-5 Housing

INCH

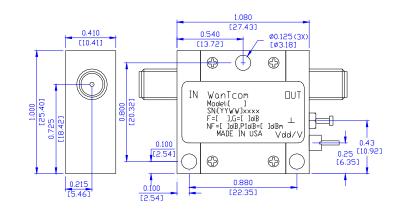
[mm]

Brass

Gold Plating SMA F Gold

Feed through

UNITS: BODY: Finish: RF Connector: V_{dd} PWR:



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WBA0105B 100 – 550 MHz LOW NOISE WIDE BAND 1 Watt AMPLIFIER

Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with $5 \sim 6$ inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connectors. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped length should be around 0.100° to 0.200° . The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped wire about 3/4 to 1 turn on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering joint by a Q-tip with alcohol to remove the flux and residue.

Do not use large soldering iron tip with more than 750 degree Fahrenheit to solder the wire and feed thru pin. Damage may occur to the feed thru. 0.010" size tip with 750 degree Fahrenheit temperature setting is suitable for the soldering works.

Repeat the process to solder the DC return wire on the ground turret. Higher temperature and larger tip can be used for this ground soldering.

C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening. Always use the appropriate torque setting of the power screwdriver to mount screws.

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